NSN 5961-01-508-3330

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-508-3330 **Inclosure Material:** Plastic **Overall Length:** Between 4.0 millimeters and 4.5 millimeters **Overall Height:** Between 1.9 millimeters and 2.4 millimeters **Overall Width:** Between 3.3 millimeters and 3.9 millimeters **End Application:** Air combat maneuvering instrumentation (acmi) **Mounting Facility Quantity:** 2 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 10.30 amperes source cutoff current universal **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector preset **Product Name:** Transient voltage suppressor diode **Terminal Type And Quantity:** 2 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig: A110a0